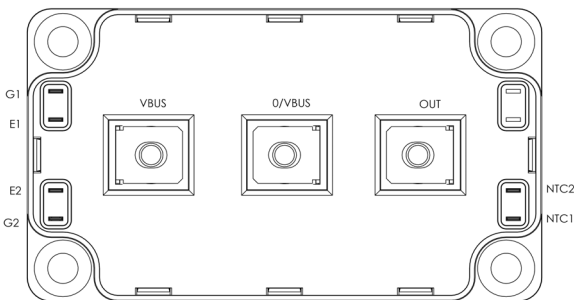
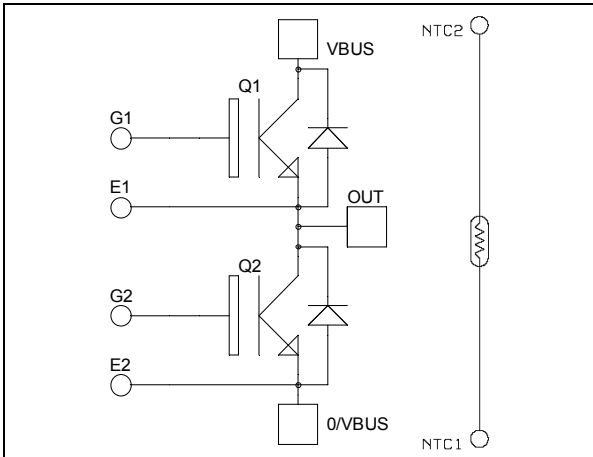


Phase leg
High speed Trench + Field Stop IGBT4
Power module

$V_{CES} = 1200V$
 $I_C = 400A @ T_c = 80^\circ C$



Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- High speed Trench + Field Stop IGBT 4 Technology
 - Low voltage drop
 - Low leakage current
 - Low switching losses
 - Soft recovery parallel diodes
 - Low diode VF
 - RBSOA and SCSOA rated

- Kelvin source for easy drive
- Very low stray inductance
- M5 power connectors
- High level of integration
- Internal thermistor for temperature monitoring

Benefits

- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- RoHS Compliant

All ratings @ $T_j = 25^\circ C$ unless otherwise specified

Absolute maximum ratings (per IGBT)

Symbol	Parameter	Max ratings	Unit
V_{CES}	Collector - Emitter Voltage	1200	V
I_C	Continuous Collector Current	$T_c = 25^\circ C$	625
		$T_c = 80^\circ C$	400
I_{CM}	Pulsed Collector Current	$T_c = 25^\circ C$	1250
V_{GE}	Gate - Emitter Voltage	± 20	V
P_D	Maximum Power Dissipation	$T_c = 25^\circ C$	1900
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125^\circ C$	800A @ 1100V

 **CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

Electrical Characteristics (per IGBT)

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$			200	μA
$V_{CE(sat)}$	Collector Emitter saturation Voltage	$V_{GE} = 15V$ $I_C = 400A$		2.05 2.6	2.4	V
		$T_j = 25^\circ C$ $T_j = 150^\circ C$				
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 14 mA$	5.2	5.8	6.4	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$			680	nA

Dynamic Characteristics (per IGBT)

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
C_{ies}	Input Capacitance	$V_{GE} = 0V$		24.6		nF
C_{oes}	Output Capacitance	$V_{CE} = 25V$		1.4		
C_{res}	Reverse Transfer Capacitance	$f = 1MHz$		1.2		
Q_G	Gate charge	$V_{GE} = 15V ; V_{CE} = 960V$ $I_C = 400A$		1800		nC
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching ($25^\circ C$) $V_{GE} = \pm 15V$ $V_{CE} = 600V$ $I_C = 400A$ $R_G = 1.25\Omega$		30		ns
T_r	Rise Time			57		
$T_{d(off)}$	Turn-off Delay Time			290		
T_f	Fall Time			16		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching ($150^\circ C$) $V_{GE} = \pm 15V$ $V_{CE} = 600V$ $I_C = 400A$ $R_G = 1.25\Omega$		30		ns
T_r	Rise Time			49		
$T_{d(off)}$	Turn-off Delay Time			366		
T_f	Fall Time			48		
E_{on}	Turn-on Switching Energy	$V_{GE} = \pm 15V$ $V_{CE} = 600V$ $I_C = 400A$ $R_G = 1.25\Omega$	$T_j = 150^\circ C$	36		mJ
E_{off}	Turn-off Switching Energy		$T_j = 150^\circ C$	22		mJ
I_{sc}	Short Circuit data	$V_{GE} \leq 15V ; V_{Bus} = 600V$ $t_p \leq 10\mu s ; T_j = 150^\circ C$		1400		A
R_{thJC}	Junction to Case Thermal Resistance				0.08	$^\circ C/W$

Diode ratings and characteristics (per diode)

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit	
V_{RRM}	Repetitive Reverse Voltage				1200	V	
I_{RM}	Reverse Leakage Current	$V_R = 1200V$			250	μA	
I_F	DC Forward Current		$T_C = 50^\circ C$	400		A	
V_F	Diode Forward Voltage	$I_F = 400A$ $V_{GE} = 0V$	$T_j = 25^\circ C$ $T_j = 150^\circ C$	1.9 1.85	2.2	V	
t_{rr}	Reverse Recovery Time	$I_F = 400A$ $V_R = 600V$ $di/dt = 7000A/\mu s$	$T_j = 25^\circ C$ $T_j = 150^\circ C$	155 300		ns	
Q_{rr}	Reverse Recovery Charge		$T_j = 25^\circ C$ $T_j = 150^\circ C$	37.2 78			μC
E_r	Reverse Recovery Energy		$T_j = 25^\circ C$ $T_j = 150^\circ C$	16 32		mJ	
R_{thJC}	Junction to Case Thermal Resistance						0.14

Temperature sensor NTC (see application note APT0406 on www.microsemi.com).

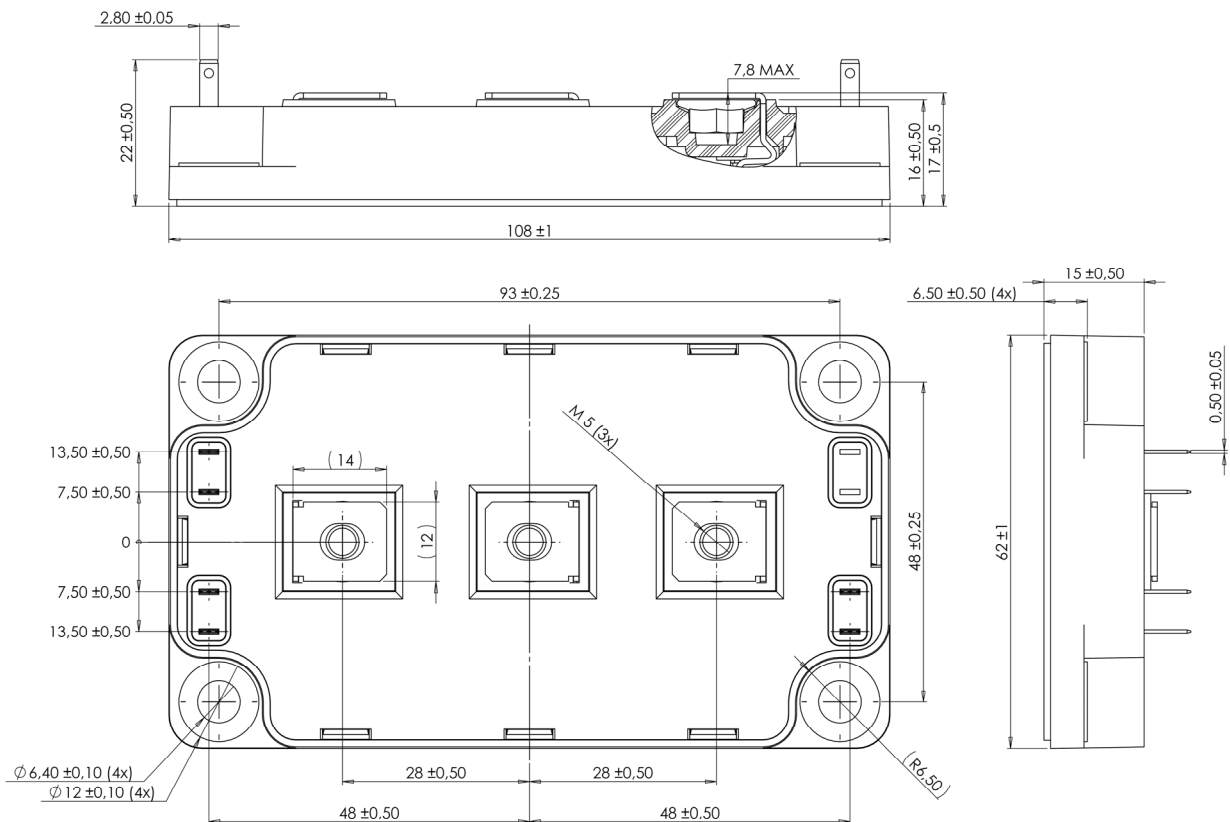
Symbol	Characteristic	Min	Typ	Max	Unit
R ₂₅	Resistance @ 25°C		50		kΩ
ΔR ₂₅ /R ₂₅			5		%
B _{25/85}	T ₂₅ = 298.15 K		3952		K
ΔB/B	T _C = 100°C		4		%

$$R_T = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$$

T: Thermistor temperature
 R_T: Thermistor value at T

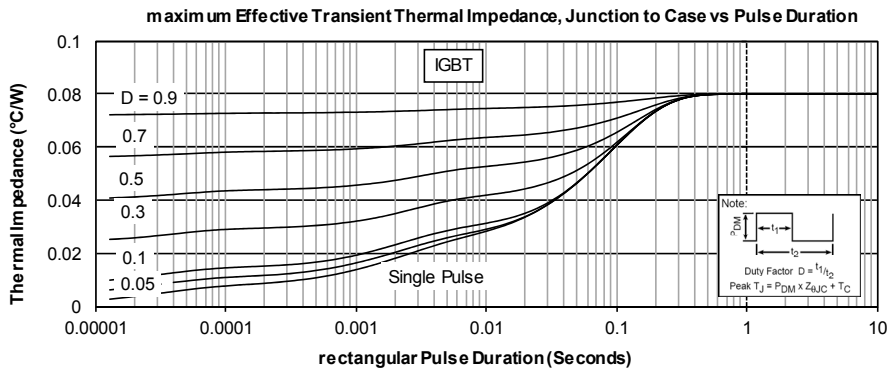
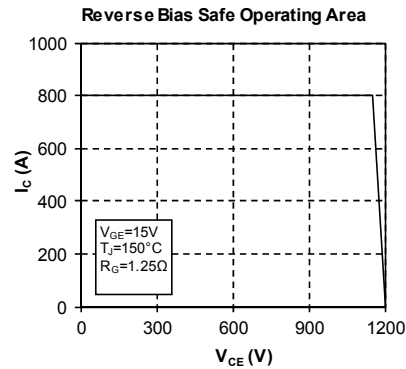
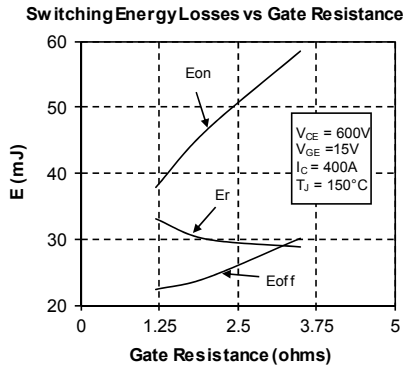
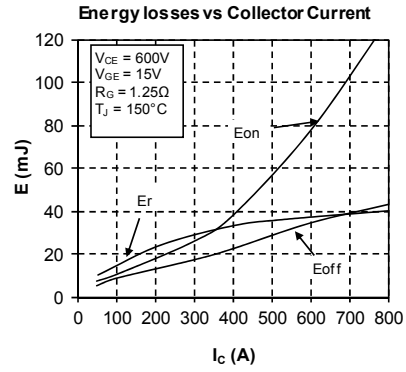
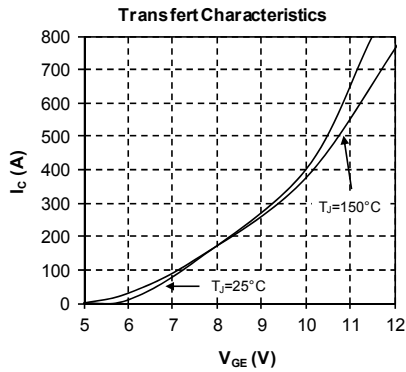
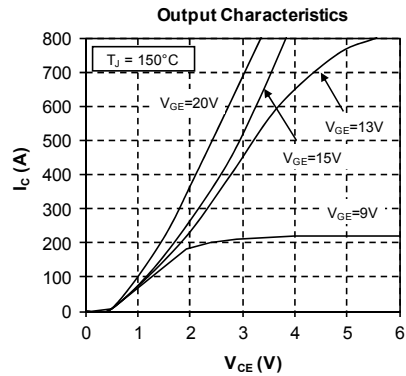
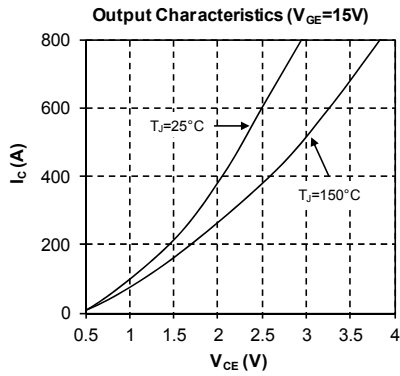
Thermal and package characteristics

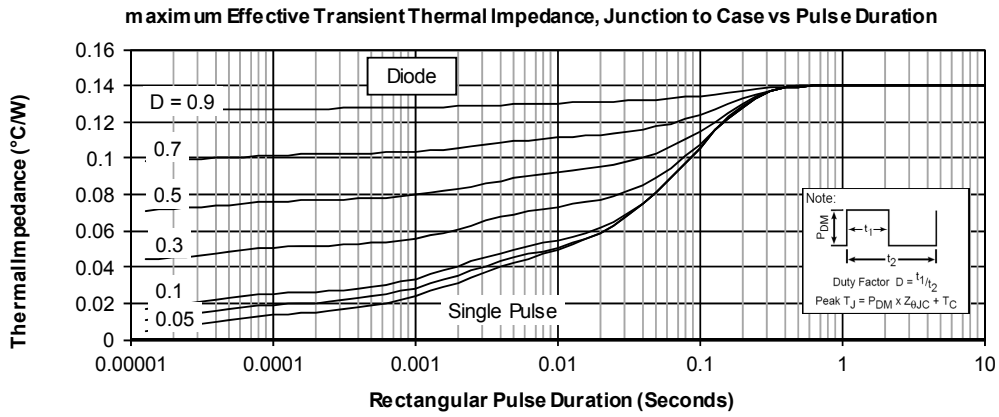
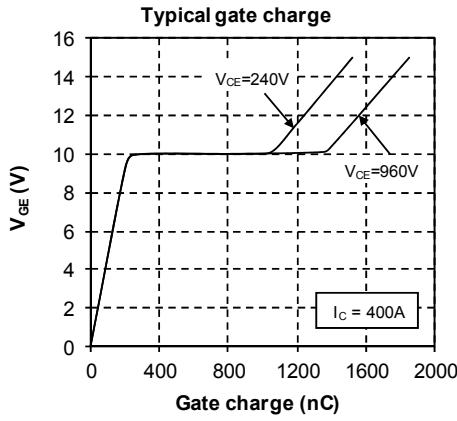
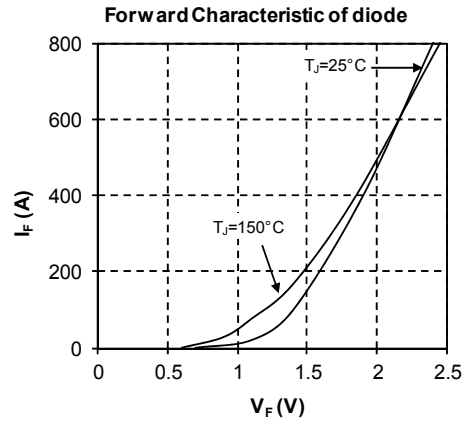
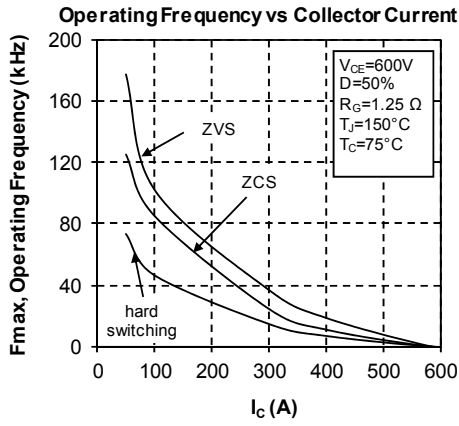
Symbol	Characteristic	Min	Max	Unit	
V _{ISOL}	RMS Isolation Voltage, any terminal to case t=1 min, 50/60Hz	4000		V	
T _J	Operating junction temperature range	-40	175	°C	
T _{JOP}	Recommended junction temperature under switching conditions	-40	T _{Jmax} -25		
T _{STG}	Storage Temperature Range	-40	125		
T _C	Operating Case Temperature	-40	100		
Torque	Mounting torque	To Heatsink	M6	3	N.m
		For terminals	M5	2	
Wt	Package Weight			300	g

Package outline (dimensions in mm)


See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

Typical Performance Curve





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